2.5 V/3.3 V ECL Differential Receiver/Driver

MC10LVEP16, MC100LVEP16

Description

The MC10/100LVEP16 is a world class differential receiver/driver. The device is functionally equivalent to the EL16, EP16 and LVEL16 devices. With output transition times significantly faster than the EL16 and LVEL16, the LVEP16 is ideally suited for interfacing with high frequency and low voltage (2.5 V) sources. Single-Ended CLK input operation is limited to a $V_{CC} \ge 3.0$ V in PECL mode, or $V_{EE} \le -3.0$ V in NECL mode.

The V_{BB} pin, an internally generated Voltage supply, is available to this device only. For Single-Ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μ F capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

The 100 Series contains temperature compensation.

Features

- 240 ps Propagation Delay
- Maximum Frequency = > 4 GHz Typical
- PECL Mode Operating Range: V_{CC} = 2.375 V to 3.8 V with V_{EE} = 0 V
- NECL Mode Operating Range: V_{CC} = 0 V with V_{EE} = -2.375 V to -3.8 V
- V_{BB} Output
- Open Input Default State
- LVDS Input Compatible
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

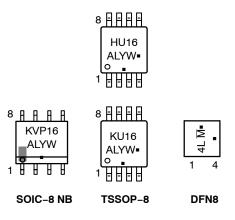


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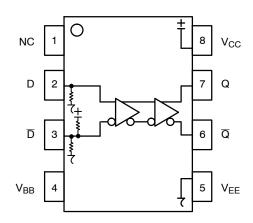


Н	= MC10	L	= Wafer Lot
κ	= MC100	Υ	= Year
4L	= MC100	W	= Work Week
М	= Date Code	•	= Pb-Free Package
А	= Assembly Lo	cati	on
(No	te: Microdot ma	ıv be	e in either location)

*For additional marking information, refer to Application Note <u>AND8002/D</u>.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 7 of this data sheet.



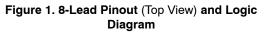


Table 1. PIN DESCRIPTION

Pin	Function
D*, <u>D</u> **	ECL Data Inputs
Q, <u>Q</u>	ECL Data Outputs
V _{BB}	Ref. Voltage Output
V _{CC}	Positive Supply
V _{EE}	Negative Supply
NC	No Connect
EP	(DFN8 only) Thermal exposed pad must be connected to a sufficient thermal con- duit. Electrically connect to the most neg- ative supply (GND) or leave unconnec- ted, floating open.

* Pins will default LOW when left open. **Pins will default to $V_{CC}\!/2$ when left open.

Table 2. ATTRIBUTES

Characteristics	Value
Internal Input Pulldown Resistor	75 kΩ
Internal Input Pullup Resistor	37.5 kΩ
ESD Protection Human Body Model Machine Model Charged Device Model	> 4 kV > 200 V > 2 kV
Moisture Sensitivity, Indefinite Time Out of Drypack (Note 1)	Pb-Free Pkg
SOIC-8 NB TSSOP-8 DFN8	Level 1 Level 3 Level 1
Flammability Rating Oxygen Index: 28 to 34	UL 94 V–0 @ 0.125 in
Transistor Count	167 Devices
Meets or exceeds JEDEC Spec EIA/JESD78 IC Latchup Test	

1. For additional information, see Application Note AND8003/D.

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V _{CC}	PECL Mode Power Supply	V _{EE} = 0 V		6	V
V_{EE}	NECL Mode Power Supply	V _{CC} = 0 V		-6	V
VI	PECL Mode Input Voltage NECL Mode Input Voltage	V _{EE} = 0 V V _{CC} = 0 V	$\begin{array}{l} V_{I} \leq V_{CC} \\ V_{I} \geq V_{EE} \end{array}$	6 -6	V
I _{out}	Output Current	Continuous Surge		50 100	mA
I _{BB}	V _{BB} Sink/Source			±0.5	mA
T _A	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			–65 to +150	°C
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	SOIC-8 NB SOIC-8 NB	190 130	°C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	SOIC-8 NB	41 to 44	°C/W
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	TSSOP-8 TSSOP-8	185 140	°C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	Standard Board	TSSOP-8	41 to 44	°C/W
θ_{JA}	Thermal Resistance (Junction-to-Ambient)	0 lfpm 500 lfpm	DFN8 DFN8	129 84	°C/W
θ_{JC}	Thermal Resistance (Junction-to-Case)	(Note 1)	DFN8	35 to 40	°C/W
T _{sol}	Wave Solder (Pb-Free)	< 2 to 3 sec @ 260°C	1 1	265	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. JEDEC standard multilayer board - 2S2P (2 signal, 2 power).

Table 4. 10EP DC CHARACTERISTICS, PECL (V_{CC} = 2.5 V, V_{EE} = 0 V (Note 1))

		−40°C				25°C		85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	17	22	27	17	22	27	17	22	28	mA
V _{OH}	Output HIGH Voltage (Note 2)	1365	1490	1615	1430	1555	1680	1490	1615	1740	mV
V _{OL}	Output LOW Voltage (Note 2)	565	740	865	630	805	930	690	865	990	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Notes 3, 4)	1.2		2.5	1.2		2.5	1.2		2.5	V
I _{IH}	Input HIGH Current			150			150			150	μA
Ι _{ΙL}	Input LOW Current D D	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.125 V to -1.3 V. 2. All loading with 50 Ω to V_{CC} - 2.0 V. 3. Do not use V_{BB} at V_{CC} < 3.0 V. Single ended input CLK pin operation is limited to V_{CC} ≥ 3.0 V in PECL mode. 4. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input sized. input signal.

			−40°C			25°C		85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	17	22	27	17	22	27	17	22	28	mA
V _{OH}	Output HIGH Voltage (Note 2)	2165	2290	2415	2230	2355	2480	2290	2415	2540	mV
V _{OL}	Output LOW Voltage (Note 2)	1365	1540	1665	1430	1605	1730	1490	1665	1790	mV
V _{IH}	Input HIGH Voltage (Single Ended)	2090		2415	2155		2480	2215		2540	mV
V _{IL}	Input LOW Voltage (Single Ended)	1365		1690	1430		1755	1490		1815	mV
V_{BB}	Output Voltage Reference (Note 3)	1790	1890	1990	1855	1955	2055	1915	2015	2115	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 4)	1.2		3.3	1.2		3.3	1.2		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μA
Ι _{ΙL}	Input LOW Current D D	0.5 -150			0.5 -150			0.5 -150			μΑ

Table 5. 10EP DC CHARACTERISTICS, PECL (V_{CC} = 3.3 V, V_{EE} = 0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.925 V to -0.5 V.

2. All loading with 50 Ω to V_{CC} – 2.0 V.

3. Single ended input CLK pin operation is limited to $V_{CC} \ge 3.0$ V in PECL mode.

4. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

-40°C 85°C 25°C Symbol Characteristic Unit Min Тур Max Min Тур Max Min Тур Max Power Supply Current 17 22 27 17 22 27 17 22 28 mΑ IEE VOH Output HIGH Voltage (Note 2) -1070 -1010 -1135 -1010 -885 -945 -820 -885 -760 mV -1935 Output LOW Voltage (Note 2) -1760 -1635 -1870 -1695 -1570 -1810 -1635 -1510 VOL mV VIH Input HIGH Voltage (Single Ended) -1210 -885 -1145 -820 -1085 -760 mV VII Input LOW Voltage (Single Ended) -1935 -1610 -1870 -1545 -1810 -1485 mV V_{BB} Output Voltage Reference (Note 3) -1510 -1410 -1310 -1445 -1345 -1245 -1385 -1285 -1185 mV Input HIGH Voltage Common Mode v VIHCMR V_{EE}+1.2 0.0 V_{EE}+1.2 0.0 V_{EE}+1.2 0.0 Range (Differential Configuration) (Note 4) Input HIGH Current 150 150 150 Ι_Η μΑ Input LOW Current μA I_{IL} D 0.5 0.5 0.5 -150 D -150 -150

Table 6. 10EP DC CHARACTERISTICS, NECL (V_{CC} = 0 V, V_{EE} = -3.8 V to -2.375 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V_{CC}.

2. All loading with 50 Ω to V_{CC} – 2.0 V.

3. Single ended input CLK pin operation is limited to V_{EE} \leq -3.0 V in NECL mode.

4. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

			−40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	19	24	29	22	28	34	24	30	36	mA
V _{OH}	Output HIGH Voltage (Note 2)	1355	1480	1605	1355	1480	1605	1355	1480	1605	mV
V _{OL}	Output LOW Voltage (Note 2)	555	730	900	555	730	900	555	730	900	mV
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential Configuration) (Notes 3, 4)	1.2		3.3	1.2		3.3	1.2		3.3	V
I _{IH}	Input HIGH Current			150			150			150	μA
Ι _{ΙĽ}	Input LOW Current D D	0.5 -150			0.5 -150			0.5 -150			μΑ

Table 7. 100EP DC CHARACTERISTICS, PECL (V_{CC} = 2.5 V, V_{EE} = 0 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary +0.125 V to -1.3 V.

2. All loading with 50 Ω to V_{CC} – 2.0 V. 3. Do not use V_{BB} at V_{CC} < 3.0 V. Single ended input CLK pin operation is limited to V_{CC} ≥ 3.0 V in PECL mode. 4. V_{IHCMR} min varies 1:1 with V_{EE}, V_{IHCMR} max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal.

			-40°C			25°C		85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	19	24	29	22	28	34	24	30	36	mA
V _{OH}	Output HIGH Voltage (Note 2)	2155	2280	2405	2155	2280	2405	2155	2280	2405	mV
V _{OL}	Output LOW Voltage (Note 2)	1355	1530	1700	1355	1530	1700	1355	1530	1700	mV
V _{IH}	Input HIGH Voltage (Single Ended)	2135		2420	2135		2420	2135		2420	mV
V _{IL}	Input LOW Voltage (Single Ended)	1355		1700	1355		1700	1355		1700	mV
V_{BB}	Output Voltage Reference (Note 3)	1775	1875	1975	1775	1875	1975	1775	1875	1975	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 4)	1.2		3.3	1.2		3.3	1.2		3.3	V
Ι _{ΙΗ}	Input HIGH Current			150			150			150	μA
Ι _{ΙL}	Input LOW Current D D	0.5 -150			0.5 -150			0.5 -150			μΑ

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V_{CC} . V_{EE} can vary +0.925 V to -0.5 V.

2. All loading with 50 Ω to V_{CC} – 2.0 V. 3. Single ended input CLK pin operation is limited to V_{CC} \ge 3.0 V in PECL mode.

4. VIHCMR min varies 1:1 with VEE, VIHCMR max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input signal.

			–40°C			25°C					
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
I _{EE}	Power Supply Current	19	24	29	22	28	34	24	30	36	mA
V _{OH}	Output HIGH Voltage (Note 2)	-1145	-1020	-895	-1145	-1020	-895	-1145	-1020	-895	mV
V _{OL}	Output LOW Voltage (Note 2)	-1945	-1770	-1600	-1945	-1770	-1600	-1945	-1770	-1600	mV
V _{IH}	Input HIGH Voltage (Single Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage (Single Ended)	-1945		-1600	-1945		-1600	-1945		-1600	mV
V_{BB}	Output Voltage Reference (Note 3)	-1525	-1425	-1325	-1525	-1425	-1325	-1525	-1425	-1325	mV
VIHCMR	Input HIGH Voltage Common Mode Range (Differential Configuration) (Note 4)	V _{EE}	V _{EE} +1.2		V _{EE} +1.2		0.0	V _{EE}	+1.2 0.0		V
I _{IH}	Input HIGH Current			150			150			150	μA
Ι _{ΙL}	Input LOW Current D D	0.5 -150			0.5 -150			0.5 -150			μΑ

Table 9. 100EP DC CHARACTERISTICS, NECL (V_{CC} = 0 V, V_{EE} = -3.8 V to -2.375 V (Note 1))

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Input and output parameters vary 1:1 with V_{CC}.

2. All loading with 50 Ω to V_{CC} – 2.0 V.

3. Single ended input CLK pin operation is limited to V_{EE} \leq -3.0 V in NECL mode.

4. VIHCMR min varies 1:1 with VEE, VIHCMR max varies 1:1 with VCC. The VIHCMR range is referenced to the most positive side of the differential input signal.

		-40°C				25°C		85°C			
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Frequency (See Figure 2. F _{max} /JITTER)		> 4			> 4			> 4		GHz
t _{PLH} , t _{PHL}	Propagation Delay to Output Differential	150	220	300	170	240	320	190	260	330	ps
t _{SKEW}	Duty Cycle Skew (Note 2)		5.0	20		5.0	20		5.0	20	ps
UITTER	CLOCK Random Jitter (RMS) @ ≤ 1.0 GHz @ ≤ 1.5 GHz @ ≤ 2.0 GHz @ ≤ 2.5 GHz @ ≤ 3.0 GHz @ ≤ 3.5 GHz		0.134 0.077 0.115 0.117 0.122 0.123	0.2 0.2 0.2 0.2 0.2 0.2 0.2		0.147 0.104 0.141 0.132 0.143 0.145	0.3 0.3 0.3 0.3 0.3 0.3		0.166 0.145 0.153 0.156 0.177 0.202	0.3 0.3 0.3 0.3 0.3 0.3	ps
V _{PP}	Input Voltage Swing (Differential Configuration)	150	800	1200	150	800	1200	150	800	1200	mV
t _r t _f	Output Rise/Fall Times Q, \overline{Q} (20% – 80%)	70	120	170	80	130	180	100	150	200	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm.

1. Measured using a 750 mV source, 50% duty cycle clock source. All loading with 50 Ω to V_{CC} – 2.0 V. 2. Skew is measured between outputs under identical transitions. Duty cycle skew is defined only for differential operation when the delays are measured from the cross point of the inputs to the cross point of the outputs.

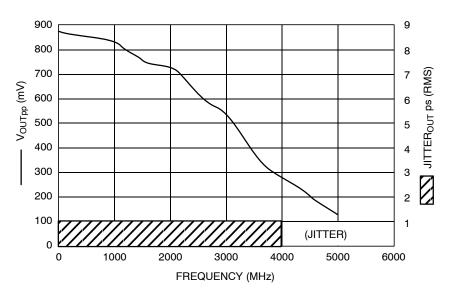
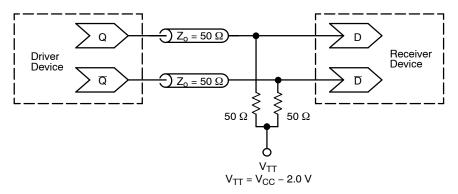


Figure 2. F_{max}/Jitter





ORDERING INFORMATION

Device	Package	Shipping [†]	
MC10LVEP16DTR2G	TSSOP-8 (Pb-Free)	2500 / Tape & Reel	
MC100LVEP16DG	SOIC-8 NB (Pb-Free)	98 Units / Tube	
MC100LVEP16DR2G	SOIC-8 NB (Pb-Free)	2500 / Tape & Reel	
MC100LVEP16DTG	TSSOP-8 (Pb-Free)	100 Units / Tube	
MC100LVEP16DTR2G	TSSOP-8 2500 / Tape & Reel (Pb-Free)		
MC100LVEP16MNR4G	DFN8 (Pb-Free)	1000 / Tape & Reel	

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, <u>BRD8011/D</u>.

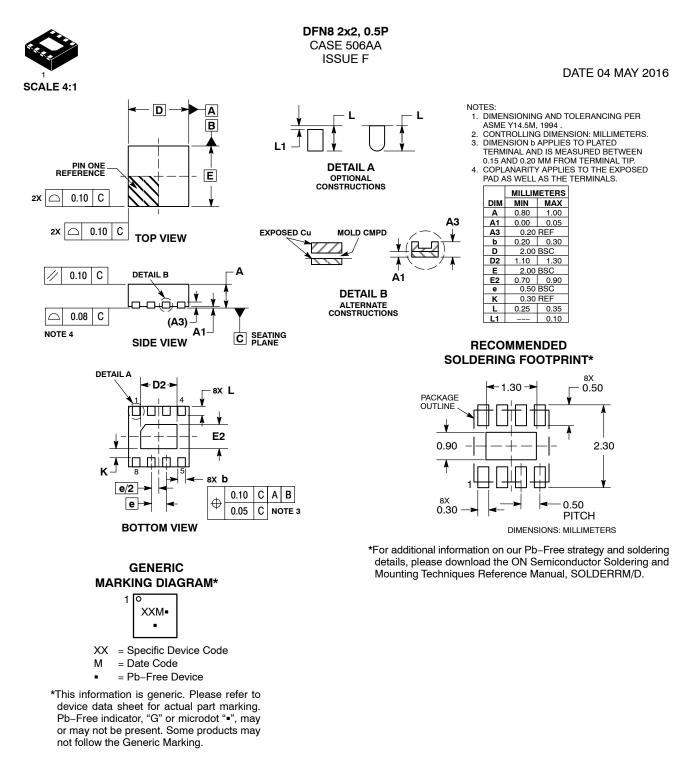
Resource Reference of Application Notes

AN1405/D	-	ECL Clock Distribution Techniques	
AN1406/D	-	Designing with PECL (ECL at +5.0 V)	
AN1503/D	-	ECLinPS [™] I/O SPiCE Modeling Kit	
AN1504/D	-	Metastability and the ECLinPS Family	
AN1568/D	-	Interfacing Between LVDS and ECL	
AN1672/D	-	The ECL Translator Guide	
AND8001/D	-	Odd Number Counters Design	
AND8002/D	-	Marking and Date Codes	
AND8020/D	-	Termination of ECL Logic Devices	

- AND8066/D Interfacing with ECLinPS
- AND8090/D AC Characteristics of ECL Devices

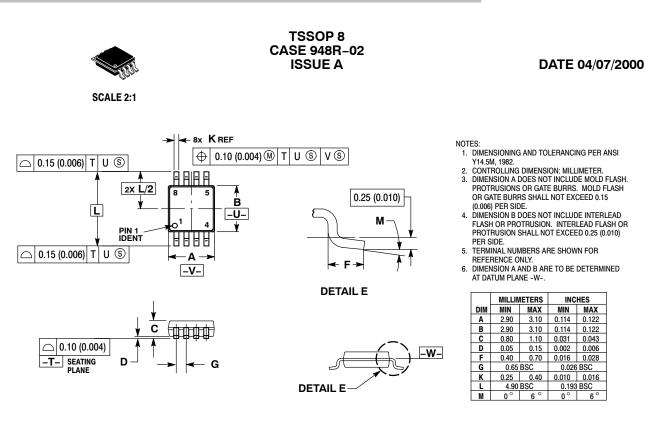
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